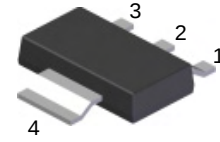


Features

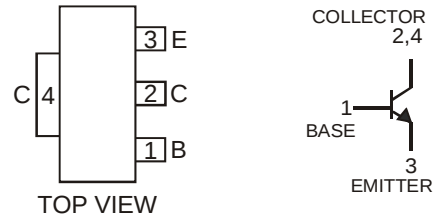
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DZT2907A)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



SOT-223

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams (approximate)



Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Continuous Current	I _C	600	mA

Thermal Characteristics

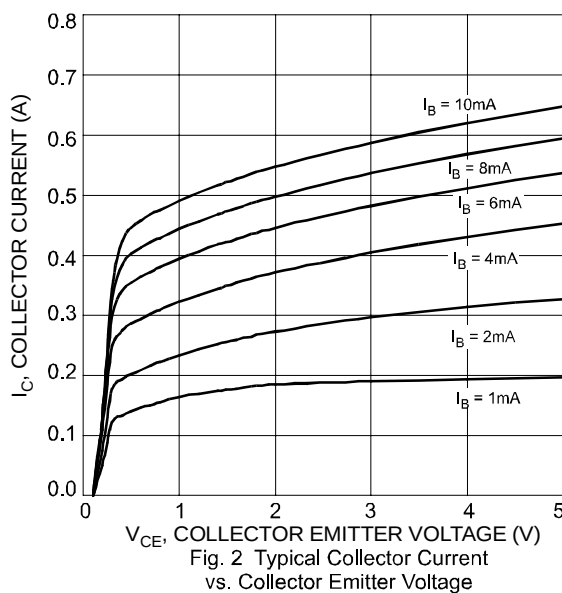
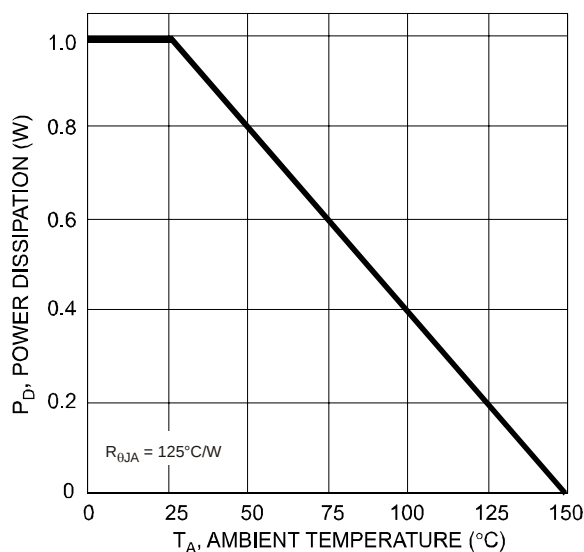
Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 3)	P _d	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @T _A = 25°C	R _{θJA}	125	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	75	—	V	I _C = 10μA, I _E = 0
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40	—	V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6	—	V	I _E = 10μA, I _C = 0
Collector Cut-Off Current	I _{CBO}	—	10	nA	V _{CB} = 50V, I _E = 0
		—	10	μA	V _{CB} = 50V, I _E = 0, T _A = 150°C
Emitter Cut-Off Current	I _{EBO}	—	10	nA	V _{EB} = 3V, I _C = 0
Collector-Emitter Cut-Off Current	I _{CEX}	—	10	nA	V _{CE} = 60V, V _{EB(off)} = 3V
ON CHARACTERISTICS (Note 4)					
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.3	V	I _C = 150mA, I _B = 15mA
		—	1.0	V	I _C = 500mA, I _B = 50mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.6	1.2	V	I _C = 150mA, I _B = 15mA
		—	2.0	V	I _C = 500mA, I _B = 50mA
DC Current Gain	h _{FE}	35	—	V	I _C = 0.1mA, V _{CE} = 10V
		50	—		I _C = 1mA, V _{CE} = 10V
		75	—		I _C = 10mA, V _{CE} = 10V
		35	—		I _C = 10mA, V _{CE} = 10V, T _A = -55°C
		100	300		I _C = 150mA, V _{CE} = 10V
		50	—		I _C = 150mA, V _{CE} = 1V
		40	—		I _C = 500mA, V _{CE} = 10V
SMALL SIGNAL CHARACTERISTICS					
Transition Frequency	f _T	300	—	MHz	I _C = 20mA, V _{CE} = 20V, f = 100MHz
Output Capacitance	C _{obo}	—	8	pF	V _{CB} = 10V, I _E = 0, f = 1MHz
Input Capacitance	C _{ibo}	—	25	pF	V _{EB} = 0.5V, I _C = 0, f = 1MHz
SWITCHING CHARACTERISTICS					
Delay Time	t _d	—	10	ns	V _{CE} = 30V, V _{EB(off)} = 0.5V, I _C = 150mA, I _{B1} = 15mA
Rise Time	t _r	—	25	ns	
Storage Time	t _s	—	225	ns	V _{CE} = 30V, I _C = 150mA, I _{B1} = I _{B2} = 15mA
Fall Time	t _f	—	60	ns	

Notes: 4. Measured under pulsed conditions. Pulse width = 300 μs. Duty Cycle, d <= 2%.



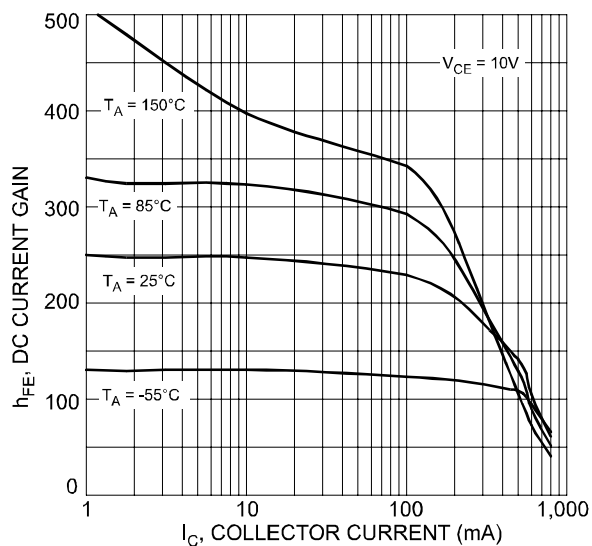


Fig. 3 Typical DC Current Gain vs. Collector Current

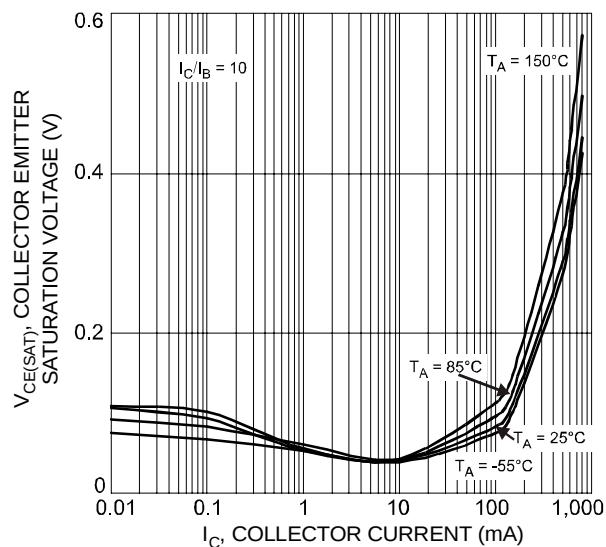


Fig. 4 Typical Collector Emitter Saturation Voltage vs. Collector Current

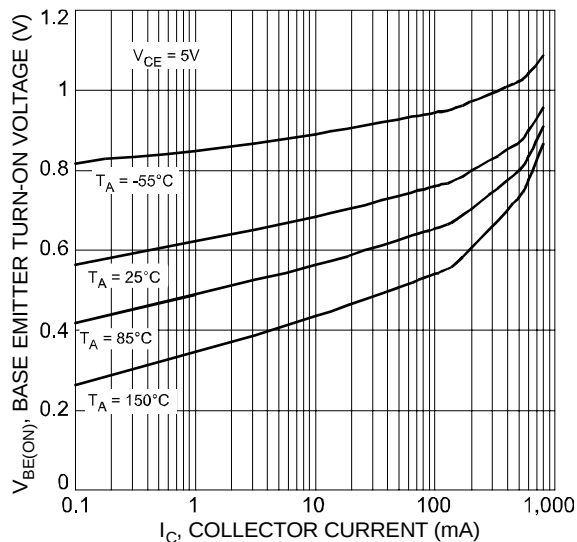


Fig. 5 Typical Base Emitter Turn-On Voltage vs. Collector Current

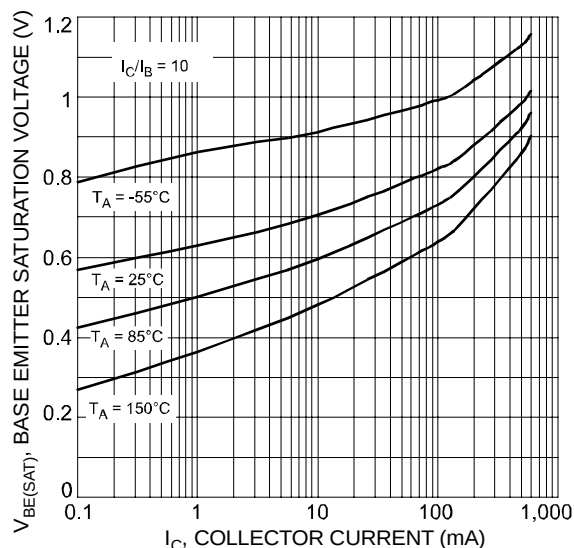


Fig. 6 Typical Base Emitter Saturation Voltage vs. Collector Current

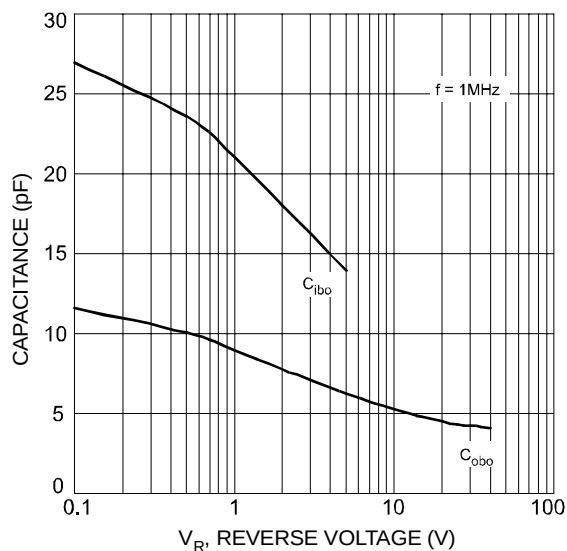


Fig. 7 Typical Capacitance Characteristics

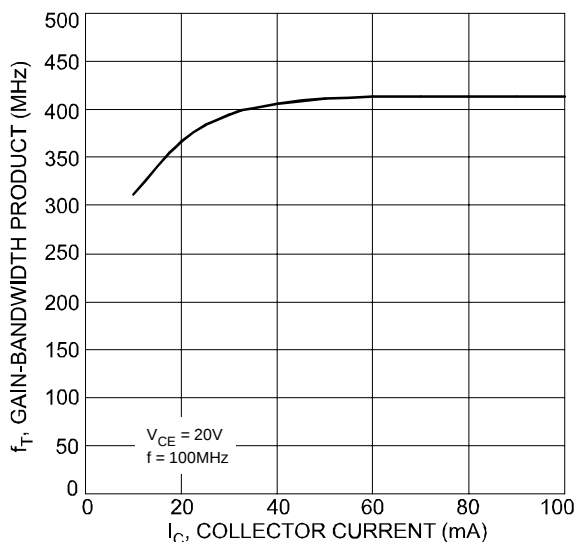


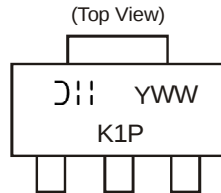
Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Ordering Information (Note 5)

Device	Packaging	Shipping
DZT2222A-13	SOT-223	2500/Tape & Reel

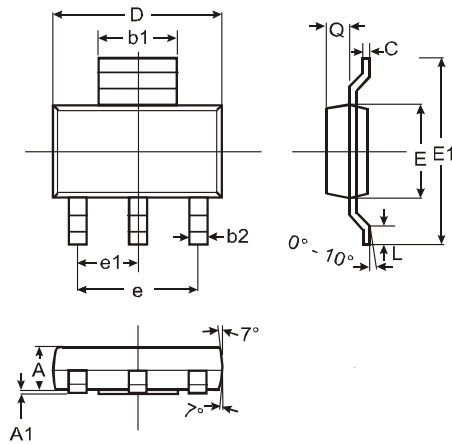
Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



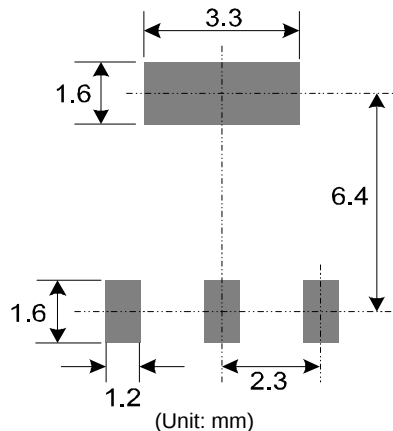
K1P = Product Type Marking Code
 YWW = Date Code Marking
 Y = Last Digit of Year ex: 7 = 2007
 WW = Week Code 01-52

Package Outline Dimensions



SOT-223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.55	0.75	0.65
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout: (Based on IPC-SM-782)



IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692
Email amall@ameya360.com
QQ 800077892
Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333
Email mkt@ameya360.com